

## Features

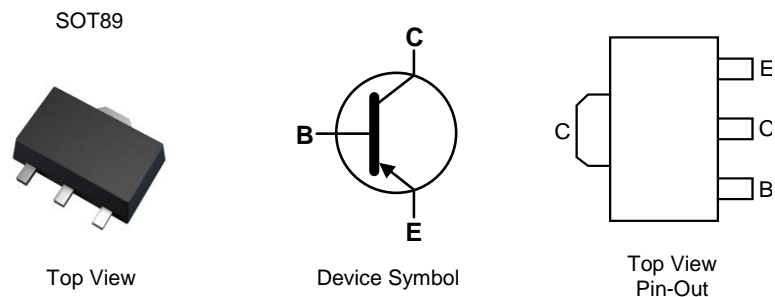
- $BV_{CEO} > -45V, -60V \text{ \& } -80V$
- $I_C = -1A$  Continuous Collector Current
- $I_{CM} = -2A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(SAT)} < -500mV @ -0.5A$
- Gain Groups 10 and 16
- Complementary NPN Types: BCX54, 55 and 56
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

## Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads; Solderable per MIL-STD-202 Method 208 (3)
- Weight: 0.052 grams (Approximate)

## Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

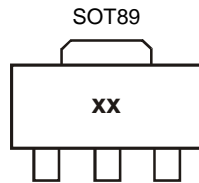


## Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCX51TA	AEC-Q101	AA	7	12	1,000
BCX51-13R	AEC-Q101	AA	13	12	4,000
BCX5110TA	AEC-Q101	AC	7	12	1,000
BCX5116TA	AEC-Q101	AD	7	12	1,000
BCX5116TC	AEC-Q101	AD	13	12	4,000
BCX52TA	AEC-Q101	AE	7	12	1,000
BCX5210TA	AEC-Q101	AG	7	12	1,000
BCX5216TA	AEC-Q101	AM	7	12	1,000
BCX5216QTA	Automotive	AM	7	12	1,000
BCX53TA	AEC-Q101	AH	7	12	1,000
BCX5310TA	AEC-Q101	AK	7	12	1,000
BCX5316TA	AEC-Q101	AL	7	12	1,000
BCX5316TC	AEC-Q101	AL	13	12	4,000
BCX5316-13R	AEC-Q101	AL	13	12	4,000
BCX5110TC	AEC-Q101	AC	13	12	4,000
BCX51TC	AEC-Q101	AA	13	12	4,000
BCX5210TC	AEC-Q101	AG	13	12	4,000
BCX5216TC	AEC-Q101	AM	13	12	4,000
BCX52TC	AEC-Q101	AE	13	12	4,000
BCX5310TC	AEC-Q101	AK	13	12	4,000
BCX53TC	AEC-Q101	AH	13	12	4,000
BCX5316QTA	Automotive	Refer to <a href="http://diodes.com/datasheets/BCX5316Q.pdf">http://diodes.com/datasheets/BCX5316Q.pdf</a>			

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



xx = Product Type Marking Code, as follows:

BCX51 = AA	BCX52 = AE	BCX53 = AH
BCX5110 = AC	BCX5210 = AG	BCX5310 = AK
BCX5116 = AD	BCX5216 = AM	BCX5316 = AL

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX51	BCX52	BCX53	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-45	-60	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	-60	-80	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5			V
Continuous Collector Current	I <sub>C</sub>	-1			A
Peak Pulse Collector Current	I <sub>CM</sub>	-2			
Continuous Base Current	I <sub>B</sub>	-100			mA
Peak Pulse Base Current	I <sub>BM</sub>	-200			

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

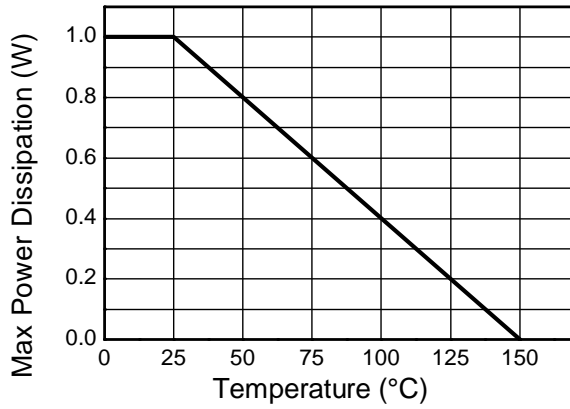
Characteristic	Symbol	Value	Unit
Power Dissipation	(Note 6)	1	W
	(Note 7)	1.5	
	(Note 8)	2.0	
Thermal Resistance, Junction to Ambient Air	(Note 6)	125	°C/W
	(Note 7)	83	
	(Note 8)	60	
Thermal Resistance, Junction to Lead	(Note 9)	13	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## ESD Ratings (Note 10)

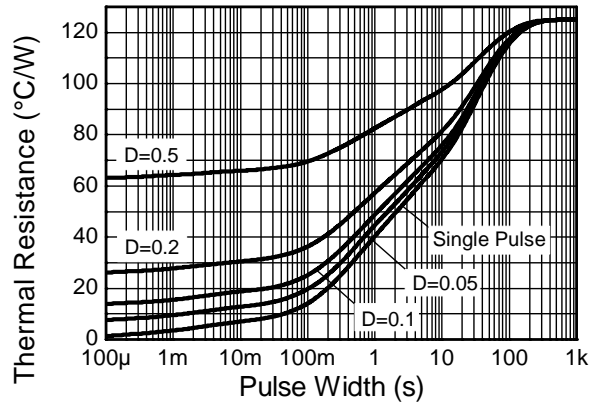
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
  8. Same as Note 6, except the device is mounted on 50mm x 50mm 1oz copper.
  9. Thermal resistance from junction to solder-point (on the exposed collector pad).
  10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

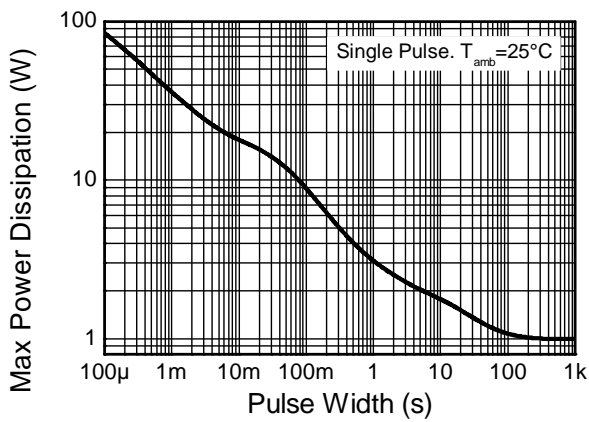
**Thermal Characteristics and Derating Information**



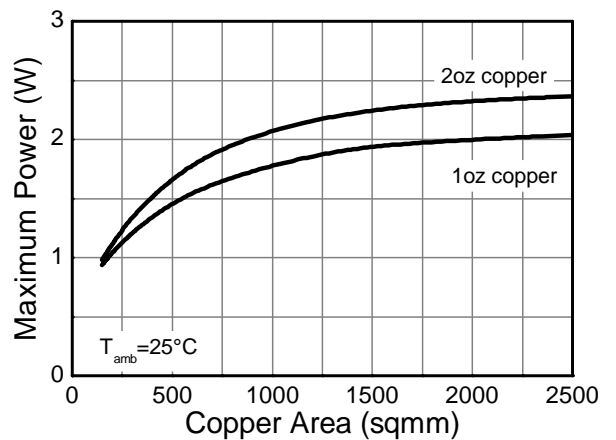
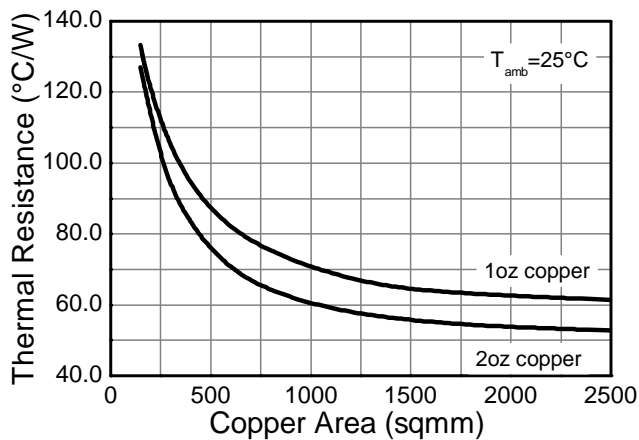
**Derating Curve**



**Transient Thermal Impedance**



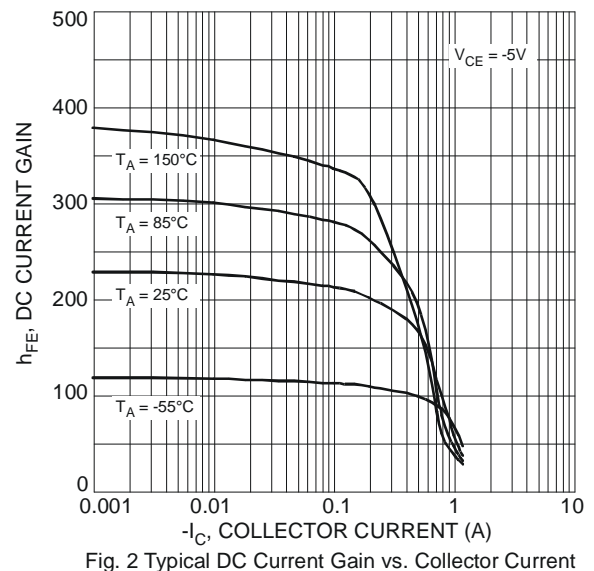
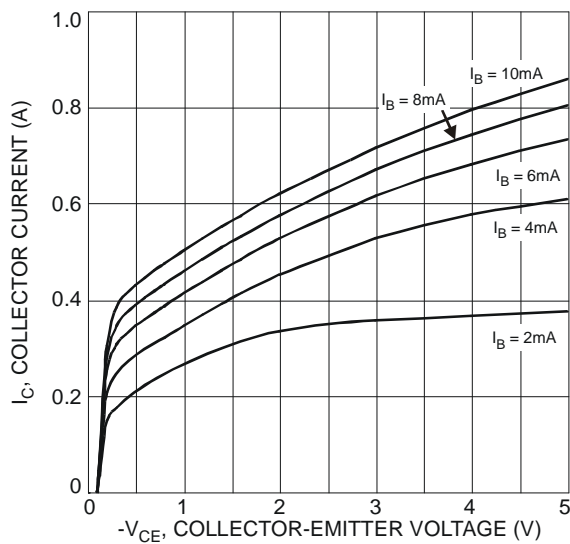
**Pulse Power Dissipation**



**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-45	—	—	V	I <sub>C</sub> = -100μA
		-60				
		-100				
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-45	—	—	V	I <sub>C</sub> = -10mA
		-60				
		-80				
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -10μA
Collector Cut-Off Current	I <sub>CBO</sub>	—	—	-0.1 -20	μA	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>J</sub> = +150°C
Emitter Cut-Off Current	I <sub>EBO</sub>	—	—	-20	nA	V <sub>EB</sub> = -5V
Static Forward Current Transfer Ratio (Note 11)	h <sub>FE</sub>	25	—	—	—	I <sub>C</sub> = -5mA, V <sub>CE</sub> = -2V I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		40				
		25				
		63				
	10 gain grp	63	—	160	I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V	
	16 gain grp	100	—	250	I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V	
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	—	—	-0.5	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	—	—	-1.0	V	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
Transition Frequency	f <sub>T</sub>	150	—	—	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	—	25	pF	V <sub>CB</sub> = -10V, f = 1MHz

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.



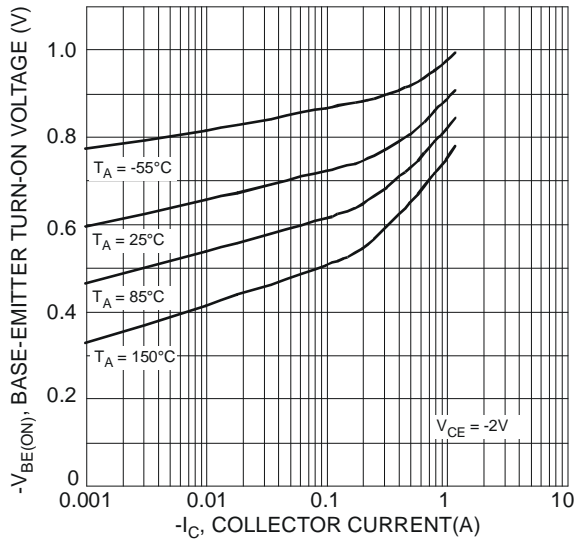


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

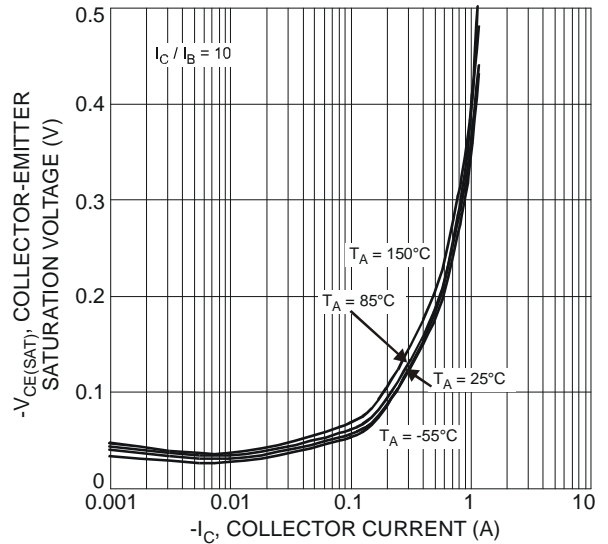


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

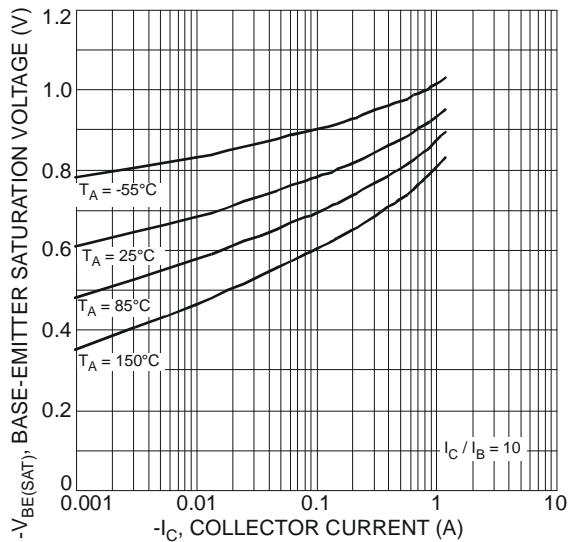


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

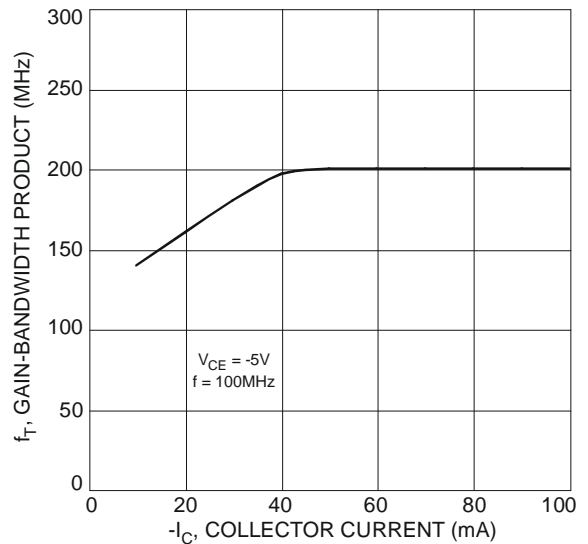


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current

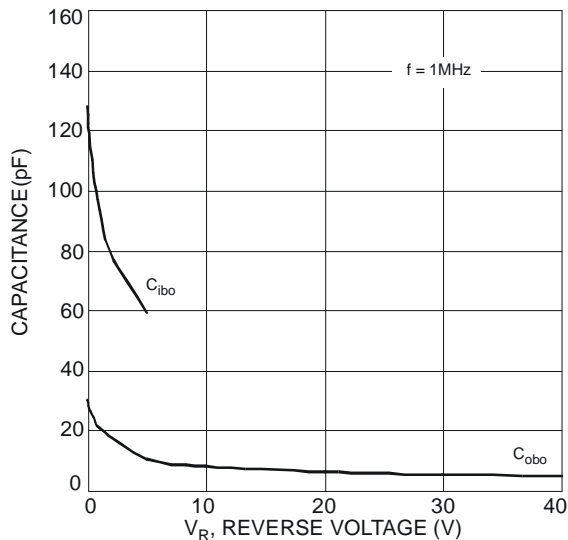
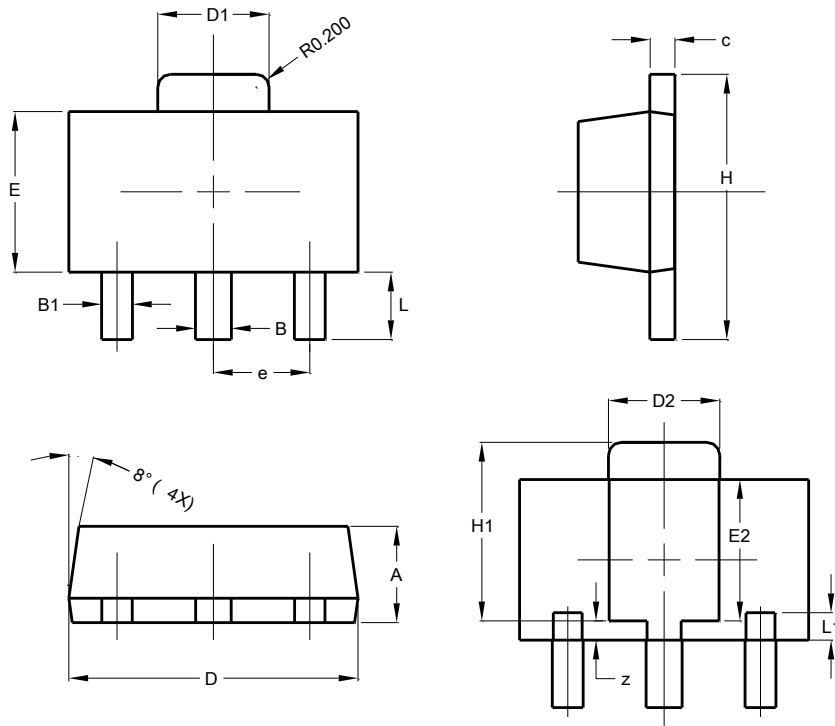


Fig. 7 Typical Capacitance Characteristics

## Package Outline Dimensions

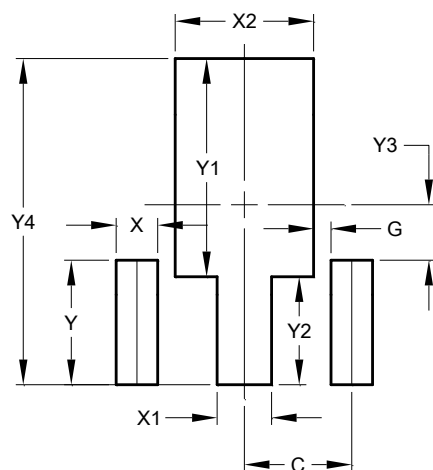
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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